

isc Silicon PNP Power Transistor

2SB1353

DESCRIPTION

- · Good Linearity of hFE
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -120V(Min)
- Complement to Type 2SD2033
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

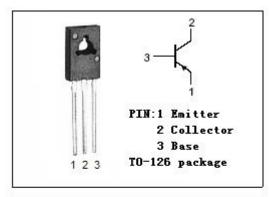


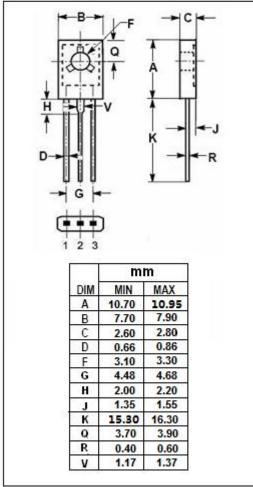
APPLICATIONS

• Designed for use in high voltage driver applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	llector-Base Voltage -120		
V _{CEO}	Collector-Emitter Voltage	-120	V	
V _{EBO}	Emitter-Base Voltage	-5.0	V	
Ic	Collector Current-Continuous -1.5			
P _C	Collector Power Dissipation @ T _a =25℃	1.8	w	
	Collector Power Dissipation @T _C =25°C	20		
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C	







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = -0.1mA; I _E = 0	-120			V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA; I _B = 0	-120			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -0.1mA; I _C = 0	-5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -1A; I _B = -0.1A			-2.0	V
Ісво	Collector Cutoff Current	V _{CB} = -120V; I _E = 0			-10	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-10	μА
h _{FE}	DC Current Cain	I _C = -0.1A; V _{CE} = -5V	60		320	
f _T	Current-Gain—Bandwidth Product	I _C = -0.1A; V _{CE} = -5V		50		MHz

♦ h_{FE} Classifications

D	E	F
60-120	100-200	160-320

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